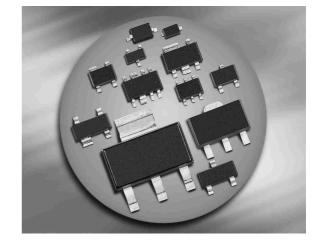


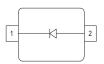
### **Silicon Variable Capacitance Diodes**

- For tuning of extended frequency band in VHF TV / VTR tuners
- High capacitance ratio
- Low series inductance
- Low series resistance
- Excellent uniformity and matching due to "in-line" matching assembly procedure
- Pb-free (RoHS compliant) package





### BB639 BB659



Туре	Package	Configuration	L <sub>S</sub> (nH)	Marking
BB639	SOD323	single	1.8	yellow S
BB659	SCD80	single	0.6	DE

### **Maximum Ratings** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	30	V
Peak reverse voltage	$V_{RM}$	35	
$(R \ge 5k\Omega)$			
Forward current	l <sub>F</sub>	20	mA
Operating temperature range	$T_{op}$	-55 150	°C
Storage temperature	$T_{\rm stg}$	-55 150	

1

2011-06-15



**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

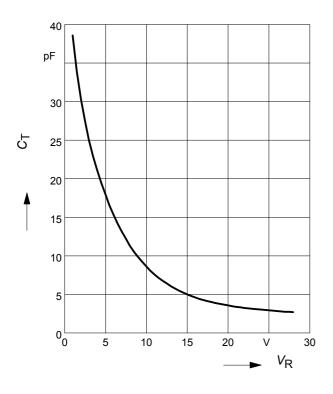
Parameter	Symbol		Unit		
		min.	typ.	max.	
DC Characteristics				•	
Reverse current	$I_{R}$				nA
V <sub>R</sub> = 30 V		-	-	10	
$V_{R}$ = 30 V, $T_{A}$ = 85 °C		-	-	200	
AC Characteristics					
Diode capacitance	C <sub>T</sub>				pF
$V_{R} = 1 \text{ V}, f = 1 \text{ MHz}$		36	38.3	40	
$V_{R} = 2 \text{ V}, f = 1 \text{ MHz}$		27.7	29.75	31.8	
$V_{R} = 25 \text{ V}, f = 1 \text{ MHz}$		2.5	2.85	3.2	
$V_{R}$ = 28 V, $f$ = 1 MHz		2.4	2.6	2.9	
Capacitance ratio	C <sub>T1</sub> /C <sub>T28</sub>	13.5	14.7	-	
$V_{R} = 1 \text{ V}, V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$					
Capacitance ratio	$C_{T2}/C_{T25}$	9.8	10.4	-	
$V_{R} = 2 \text{ V}, V_{R} = 25 \text{ V}, f = 1 \text{ MHz}$					
Capacitance matching <sup>1)</sup>	$\Delta C_{T}/C_{T}$				%
$V_{R}$ = 1 V, $V_{R}$ = 28 V, $f$ = 1 MHz, <b>7</b> diode sequen	d				
BB639		-	-	2.5	
$V_{R}$ = 1 V, $V_{R}$ = 28 V, $f$ = 1 MHz, <b>4</b> diode sequen	d				
BB659		-	0.3	1	
$V_{R}$ = 1 V, $V_{R}$ = 28 V, $f$ = 1 MHz, <b>7</b> diode sequen	d				
BB659		-	0.4	2	
Series resistance	$r_{\rm S}$	-	0.65	0.7	Ω
$V_{R} = 5 \text{ V}, f = 470 \text{ MHz}$					

<sup>&</sup>lt;sup>1</sup>For details please refer to Application Note 047.

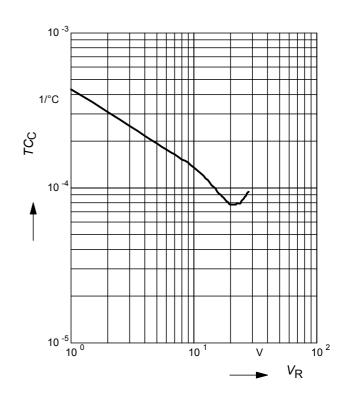


# **Diode capacitance** $C_T = f(V_R)$

f = 1MHz

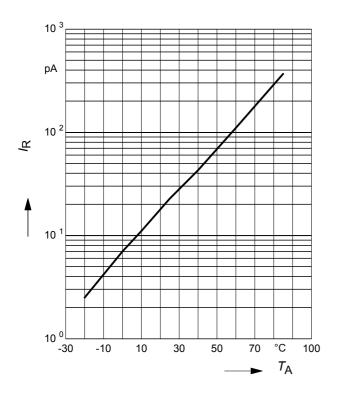


# Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



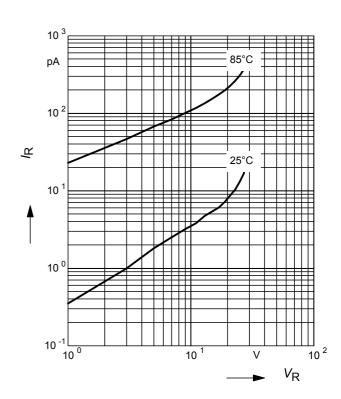
## Reverse current $I_R = f(T_A)$

 $V_{R} = 28V$ 



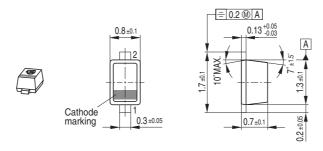
# Reverse current $I_R = f(V_R)$

 $T_A$  = Parameter





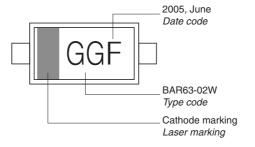
### Package Outline



### Foot Print



### Marking Layout (Example)

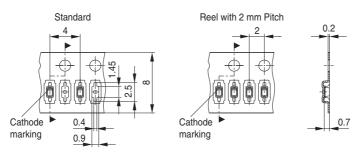


### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel

Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)

Reel ø330 mm = 10.000 Pieces/Reel



4



# Date Code marking for discrete packages with one digit (SCD80, SC79, SC75<sup>1)</sup>) CES-Code

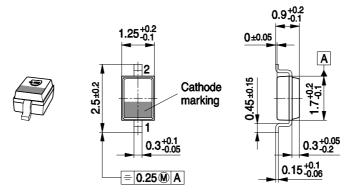
Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	Α	Р	а	р	Α	Р	а	р	Α	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	S	D	S
05	е	t	Е	T	е	t	Е	Т	е	t	Е	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	٧	G	V	g	٧	G	٧	g	٧	G	V
08	h	Х	Н	Х	h	Х	Н	Х	h	Х	Н	Х
09	j	У	J	Υ	j	у	J	Υ	j	У	J	Y
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	I	2	L	4	I	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

<sup>1)</sup> New Marking Layout for SC75, implemented at October 2005.

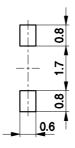
5 2011-06-15



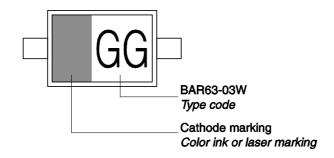
### Package Outline



### **Foot Print**

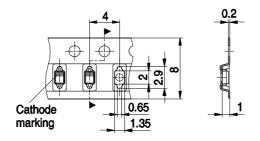


### Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



6



#### Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

### **Legal Disclaimer**

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

### Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<a href="www.infineon.com">www.infineon.com</a>).

### Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

7

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Varactor Diodes category:

Click to view products by Infineon manufacturer:

Other Similar products are found below:

MA46H201-1056 MAVR-001330-12790T MVAM108 SMV1233-079 SVC704-TL-E SVC710-TL-E 1SV324TPH3F MAVR-0000830287AT MAVR-044769-12790T SVC270-TL-E RKV501KJ#R1 MA46H204-1056 MA46H202-1088 MA46H202-1056 MA46H203-1088

MA46H203-1056 MA46H120 MA46H070-1056 SMV1275-079LF SVC272-TL-E GC2510-17 MAVR-044769-02870T MGV1252208052X

MAVR-001350-12790T SMV1251-040LF MAVR-000409-0287FT MX1977 KVX2301-23-0 KVX3901A-23-4 KVX1501-23-0 KVX2132
23-0 KVX38S2-23-0 KVX3901A-23-0 KVX2122-23-0 MPV2100-206 KVX2001-23-0 GC1213-23-0 GC15006-152 MA46603-276

SMVA1253-079LF MGV125-08-0805-2 MAVR-000079-0287FT MA46H072-1056 MA46H071-1056 MAVR-000120-12030P

BB844E6327HTSA1 BB535E7904HTSA1 BBY5303WE6327HTSA1 BBY6602VH6327XTSA1 BBY5502VH6327XTSA1